





Features

- UL Recognized File # E-326243
- Plastic material used carries Underwriters
- Laboratory Classifications 94V-0
 Metal silicon rectifier, majority carrier conduction
 Low power loss, high efficiency

- High current capability, low forward voltage drop High surge capability For use in low voltage, high frequency inverters,
- free wheeling, and polarity protection applications Guardring for overvoltage protection
 High temperature soldering guaranteed:
 260°C/10 seconds,0.25"(6.35mm)from case
 Green compound with suffix "G" on packing
- code & prefix "G" on datecode.

Mechanical Data

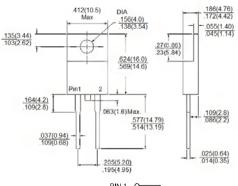
- Cases: JEDEC TO-220AC molded plastic body Terminals: Pure tin plated, lead free. solderable per MIL-STD-750, Method 2026

- Polarity: As marked Mounting position: Any Mounting torque: 5 in. lbs. max
- Weight: 1.85 grams

MBR735 - MBR7150

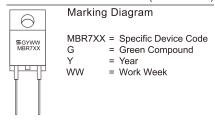
7.5 AMPS. Schottky Barrier Rectifiers

TO-220AC



PIN 2 ON CASE

Dimensions in inches and (millimeters)



Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%

Type Number	Symbol	MBR 735	MBR 745	MBR 750	MBR 760	MBR 790	MBR 7100	MBR 7150	Units
Maximum Recurrent Peak Reverse Voltage	Vrrm	35	45	50	60	90	100	150	V
Maximum RMS Voltage	VRMS	24	31	35	42	63	70	105	V
Maximum DC Blocking Voltage	VDC	35	45	50	60	90	100	150	V
Maximum Average Forward Rectified Current See Fig. 1	I F(AV)	V) 7.5							Α
Peak Repetitive Forward Current (Square Wave, 20KHz) at Tc=105°C	I FRM	15							Α
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I FSM	150							Α
Peak Repetitive Reverse Surge Current (Note 2)	RRM	1.0 0.5					Α		
Maximum Instantaneous Forward Voltage at $I_F=7.5A, T_A=25^{\circ}C$ $I_F=7.5A, T_A=125^{\circ}C$ $I_F=15A, T_A=25^{\circ}C$ $I_F=15A, T_A=125^{\circ}C$	VF	 0.57 0.84 0.72			75 65 –	0.92 0.82 —		0.95 092 —	٧
Maximum Instantaneous Reverse Current @ TA =25 °C at Rated DC Blocking Voltage (Note 1) @ TA=125 °C	I R	0.1 15.0		0	.1 0	0.1 5.0			mA mA
Voltage Rate of Change (Rated V _R)	dV/dt	10,000						V/uS	
Typical Junction Capactance	Cj	3	60	2	30	20	00	160	pF
Maximum Thermal Resistance, (Note 3)	Rejc Reja	5.0 15.0							°C/W
Operating Junction Temperature Range	TJ	-65 to +150							°C
Storage Temperature Range	Tstg	-65 to +175							°C

Notes: 1. Pulse Test: 300us Pulse Width, 1% Duty Cycle 2. 2.0us Pulse Width, f=1.0 KHz 3. Mounted on Heatsink Size of 2 in x 3 in x 0.25 in Al-Plated.

Version: F10



RATINGS AND CHARACTERISTIC CURVES (MBR735 THRU MBR7150)

